

Gas phase germylation of simple aromatics by Me₃Ge⁺ ions

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Abstract

The germylation of simple aromatic hydrocarbons has been studied by two different techniques. The Fourier Transform Ion Cyclotron Resonance (FTICR) technique allowed the study of Me₃Ge⁺ transfer equilibria between aromatics and H₂O at 300 K. The ion-molecule reaction of [Me₃Ge⁺ arene] ions with selected neutrals are accounted for by a σ -complex species, retaining the primary *ipso* structure, where the germyl group and the former aromatic hydrogen are bound to the same tetrahedral carbon. The free energies of binding of Me₃Ge⁺ to the selected aromatic compounds correlate linearly with the values of the corresponding Me₃Si⁺ reaction with a slope of 0.93. The combined information from the FTICR and radiolytic technique has revealed a mechanistic pattern for the electrophilic aromatic substitution by Me₃Ge⁺ that closely reproduces the corresponding Me₃Si⁺ reaction, the major difference lying in the greater ease of detachment of Me₃Ge⁺ by nucleophilic assistance. © 1997 Elsevier Science S.A.

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1. Introduction

In continuation of our research on the gas-phase trimethylsilylation reactions by Me₃Si⁺ ions [1-6], we have undertaken a study on the reactivity of the neighbor group IVA analogue, Me₃Ge⁺, towards (mostly) aromatic compounds aimed to compare the reactivity behavior of the two ions. Although early reports have shown that Me₃Ge⁺ may form stable adducts with a variety of organic molecules [7], this ion has never received a comparably widespread attention as Me₂Si⁺. One practical reason may be bound to the complex isotopic pattern of germanium (⁷⁰Ge, ⁷²Ge, ⁷³Ge, ⁷⁴Ge, ⁷⁶Ge, with relative abundances of 20%, 27%, 8%, 37%, 8%, respectively) which allows ready mass spectrometric identification of germylated ions but at the same time spreads the overall intensity of a single ionic species and enhances the likelihood of overlapping signals. We have used an approach based on two techniques. The first one is a mass spectrometric technique, Fourier Transform Ion Cyclotron Resonance (FTICR) [8], endowed with the powerful capability of isolating an ion of interest within a complex mixture. This ion

may be a single isotopic species or the whole isotopic cluster corresponding to a given composition. In the presence of one or more neutrals in the ICR cell, at typical pressures of 10^{-8} Torr, ion-molecule reactions can be recorded and equilibria can set up at the cell room temperature of 300 K. The second technique exploited, the radiolytic method [9], performs ion-molecule reactions at the pressure of ca. 1 atm using ionic species produced by the action of γ -radiation and yielding mechanistic information from the analysis of neutral products formed in the selected range of conditions. The combination of the two techniques has yielded a comprehensive picture of the major features of the Me₃Ge⁺ reaction with aromatic compounds.

2. Experimental

Research grade gases with stated purity in excess of 99.9% were purchased from Matheson. All other chemicals were obtained from commercial sources, including Me₄Ge from Alfa Products. They were analyzed by GC and purified by preparative GC, whenever necessary.

Gaseous samples for the radiolytic experiments were prepared by standard vacuum line techniques, as previously described [9]. The gaseous mixtures were irradi-

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ated in a 220 Gammacell (Nuclear Canada) at 40° C, to total doses ranging from 0.5×10^4 Gy to 1×10^4 Gy, at the dose rate of 1×10^4 Gy h⁻¹. The radiolytic product mixture was recovered under airtight conditions as cyclohexane solution and analyzed by GC-MS using a Hewlett-Packard 5890 gas chromatograph equipped with a 50-m long, 0.20-mm i.d. fused silica column coated with a 0.50- μ m cross-linked methyl silicone film (PONA column from Hewlett-Packard) in line with a Hewlett-Packard mass selective detector model 5970B.

The FTICR experiments were performed using a Bruker Spectrospin Apex TM 47e spectrometer equipped with an external ion source and a cylindrical (12-cm length, 12-cm diameter) 'infinity' cell situated between the poles of a 4.7 Torr superconducting magnet. This instrumental configuration allows the generation of ionic species in the external ion source where a suitable chemical ionization (CI) reagent gas is introduced. For example a CH₄/Me₄Ge (97:3 mol%) mixture at the pressure of 1×10^{-4} Torr was used to generate Me₃Ge⁺ ions which were allowed to react with a selected substrate (S = aromatic hydrocarbon, H_2O , MeOSiMe₃) introduced into the ion source by a separate inlet. The resulting ion mixture was transmitted into the FTICR cell at 300 K, where one or two different neutrals were present at stationary concentration. The ion of interest, typically Me₃GeS⁺, was isolated from the plasma by sequential broad band ejection and 'single shots' [10] and was allowed to react. Ion intensity vs. time profiles were obtained by recording mass spectra at increasing reaction time. The concentration of the neutrals was determined from the pressure reading at the ionization gauge located in the high vacuum line of the FTICR cell housing, corrected by using appropriate calibration factors [11].

3. Results

3.1. FTICR mass spectrometry

FTICR has been used in the first place to measure Me₃Ge⁺ transfer equilibria between aromatics or between an aromatic and H_2O (Eq. (1)). The experiments were performed as follows. Me₃Ge⁺ ions from the CI of CH₄/Me₄Ge in the external ion source were allowed to react with an aromatic compound (X) introduced into the same ion source at 0.1% relative concentration. Abundant adduct ions (Me₃GeX⁺) were formed. These were transferred into the FTICR cell where known concentrations of the same aromatic compound and of a reaction partner (another aromatic or H₂O) were present. An alternative route to Me₃GeX⁺ ions by reaction of Me₃Ge⁺ with an aromatic compound in the ICR cell failed to give significant abundances of adduct ions due to the inefficient collisional stabilization in the low pressure environment $(10^{-8}-10^{-7})$ Torr. The primary

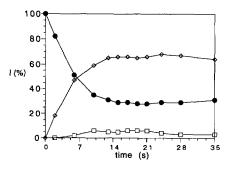


Fig. 1. Normalized ion intensities of $MeC_6H_5GeMe_3^+$ (\blacksquare), $Me_3GeOH_2^+$ (\bigcirc), and Me_3Ge^+ (\square) as a function of time. Partial pressures in the FTICR cell were: $P(toluene) = 1.5 \times 10^{-8}$ Torr and $P(H_2O) = 0.15 \times 10^{-8}$ Torr.

adduct ion was isolated from other ions which entered or were formed in the cell by resonance ejection techniques and was allowed to react with the mixture of the two neutrals for increasing reaction times (Eq. (1)):

$$Me_3GeX^+ + Y \rightleftharpoons Me_3GeY^+ + X.$$
 (1)

Plots of relative ion intensities vs. time were thus obtained, showing the attainment of equilibrium when the ion intensity ratio reaches a constant value. An example of such plots is shown in Fig. 1 where $X = \text{MeC}_6H_5$ and $Y = H_2O$. The equilibrium constant at the cell temperature of 300 K is calculated from Eq. (2) (where i are ion intensities and P are partial pressures) and yielded a ΔG_{300}° value (kcal mol⁻¹) according to Eq. (3):

$$K = \frac{i(\text{Me}_3\text{GeY}^+) \times P(X)}{i(\text{Me}_3\text{GeX}^+) \times P(Y)},$$
(2)

$$\Delta G_{300}^{\circ} = -RT \ln K = -0.60 \ln K. \tag{3}$$

The attainment of a true equilibrium is verified by the constancy of the right-hand ratio of Eq. (2) for

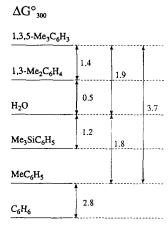


Fig. 2. Measured free energy changes, ΔG_{300}° , for Me₃Ge⁺ transfer between aromatics and H₂O. The direction of the preferred transfer (ΔG° negative) is in the upward direction. Comparison of overlapping and successive steps on the ladder show an internal consistency of about ± 2 kcal mol⁻¹. Reproducibility of ΔG° values was better than ± 1 kcal mol⁻¹.

Table 1 Free energy changes for the process $Me_3Ge^+ + X \rightleftharpoons Me_3GeX^+$

X	$-\Delta G_{300}^{\circ a}$ (kcal mol ⁻¹)	₀ (kcal mol ⁻¹)	
1,3,5-Me ₃ C ₆ H ₃	20.2		
1.3-Me ₂ C ₆ H ₄	18.8		
Me ₃ SiC ₆ H ₅	17.1		
MeC ₆ H ₅	16.5		
C_6H_6	13.7		
H_2O	18.3 ^b		

^aAverage error ± 0.1 kcal mol⁻¹.

different ratios of the partial pressures of the two neutrals. The ΔG_{300}^{c} ladder obtained in this way is displayed in Fig. 2 and was used to derive the free energies of binding of $Me_{3}Ge^{+}$ to the various compounds (reaction 4) from the known thermodynamic data relative to the $Me_{3}Ge^{+}$ association to $H_{2}O$ [12].

$$Me_3Ge^+ + X \rightleftharpoons Me_3GeX^+.$$
 (4)

The so obtained $\Delta G_{(4)}^{\circ}$ values are listed in Table 1.

The reaction of $Me_3GeC_6D_6^+$ ions, formed in the ion source by CH_4/Me_4Ge-CI of C_6D_6 , with Et_3N introduced into cell was also studied by FTICR, yielding the temporal profile of ion intensities shown in Fig. 3. The exponential decay of the reactant ion yields a bimolecular rate constant of 3.7×10^{-9} cm³ s⁻¹, corresponding exactly to the collisional rate constant [13]. This is indicative that the $Me_3GeC_6D_6^+$ ion reacts with the strong base on every collision. Among the ionic products, besides the trimethylgermylated amine at m/z 220 (⁷⁴Ge isotope), the ion at m/z 103 is significant. It corresponds to the Et_3ND^+ and shows that the reactant ion can transfer not only Me_3Ge^+ but also a deuteron to the base.

The reaction of MeO(SiMe₃)GeMe₃⁺ ions, obtained by Me₃Ge⁺ addition to MeOSiMe₃, with (MeO)₃PO, a powerful oxygen nucleophile, has been performed to check as to what relative extent Me₃Ge⁺ transfer vs. Me₃Si⁺ transfer would occur. The temporal profiles of

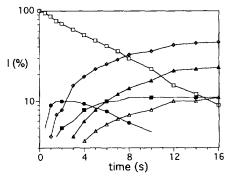


Fig. 3. Normalized ion intensities of $Me_3GeC_6D_6^+$ (\square), $Me_3GeNEt_3^+$ (\triangleleft), Et_3ND^+ (\triangle), $[Et_3N-H]^+/Et_3N^+$ (\blacksquare), Et_3NH^+ (\blacktriangle), and Me_3Ge^+ (\blacksquare) as a function of time. The pressure of Et_3N was 1.7×10^{-9} Torr.

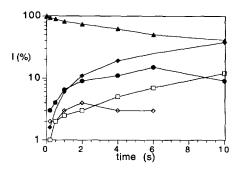


Fig. 4. Normalized ion intensities of MeO(SiMe₃)GeMe₃⁺ (\blacktriangle), (MeO)₃POGeMe₃⁺ (\spadesuit), (MeO)₃POSiMe₃⁺ (\Box), Me₃Ge⁺ (\spadesuit), and Me₃Si⁺ (\diamondsuit) as a function of time. The pressure of (MeO)₃PO was 1.2×10^{-8} Torr.

ion intensities plotted in Fig. 4 show that the heterolytic cleavage of the Ge-O bond occurs preferentially to give both the free Me₃Ge⁺ ion and a higher fraction (ca. 3:1) of the (MeO)₃POGeMe₃⁺ product ions with respect to the silicon counterpart, (MeO)₃POSiMe₃⁺.

A greater ease of Me_3Ge^+ transfer to oxygen nucle-ophiles apparently emerges also from the reaction of $Me_3SiC_6H_5GeMe_3^+$ ions, illustrated in Fig. 5, from CH_4/Me_4Ge-CI of $Me_3SiC_6H_5$, with H_2O in the ICR cell at 5.9×10^{-9} Torr. The products ions, corresponding to $Me_3GeOH_2^+$ and $Me_3GeOH(SiMe_3)^+$, are suggested both to follow from the primary product ion-neutral complex, $[Me_3GeOH_2^+ \cdot Me_3SiC_6H_5]$, by direct dissociation or further reaction within the complex (Scheme 1). Noteworthy, no $Me_3SiOH_2^+$ is formed.

3.2. Radiolytic reactions

Radiolytic germylation reactions have been performed at 40°C in a 97:3 mol% mixture of CH_4/Me_4Ge at 620 Torr, where ionization is effected by the secondary electrons following the interaction of γ -radiation with the materials (mainly the vessel glass walls) of the radiolyzed sample. Table 2 summarizes the results from the germylation of toluene and of benzene as competing

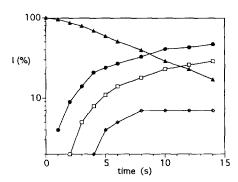


Fig. 5. Normalized ion intensities of $Me_3SiC_6H_5GeMe_3^+$ (\blacktriangle), $Me_3GeOH_2^+$ (\blacksquare), Me_3Ge^+ (\diamondsuit), and $Me_3GeOH(SiMe_3)^+$ (\square) as a function of time. The pressure of H_2O was 5.9×10^{-9} Torr.

^bRef. [12].

substrate. All systems contained a radical scavenger, O₂, at 10 Torr, whose presence allows to neglect conceivable radical pathways to the observed products.

In order to obtain germylation products from the aromatic hydrocarbons, the presence of a strong nitrogen base, such as Et₃N, with proton affinity (PA) equal to 232 kcal mol⁻¹ [14], was found to be a necessary condition. With no such additive present or when $(MeO)_3PO (PA = 212 \text{ kcal mol}^{-1}) [14] \text{ is used in the}$ place of Et₃N, no aromatic germylation takes place. The isomer distribution of the toluene products, MeC₆H₄GeMe₃, is characterized by the absence of the ortho isomer and by the distinct preference of parawith respect to meta-substitution. The series of experiments run at nearly constant amounts of benzene and toluene and varying concentrations of Et₃N yield both C₆H₅GeMe₃ and MeC₆H₄GeMe₃, whose combined yield are plotted against the Et₃N partial pressure in Fig. 6. Their relative yields can be analyzed by the standard equation for competing reactions (Eq. (5), where $G_{\rm M}$ are radiochemical yields in units of 10^{-3} μ mol J⁻¹ (note b of Table 2) to give apparent relative

Table 2 Aromatic substitution by gaseous Me₃Ge⁺ ions

System composition (Torr) ^a		Product yields $(G_{\rm M})^{\rm b}$		
C ₆ H ₆	MeC ₆ H ₅	Et ₃ N	C ₆ H ₅ GeMe ₃	$MeC_6H_4GeMe_3$ (o/m/p)
2.5	_	1.5°		
-	2.3	_		-
_	1.9	1.0°	_	
_	2.6	1.6	_	5.2 (0/18/82)
2.9	0.94	0.40	0.20	0.77 (0/24/76)
3.1	1.1	0.89	0.36	1.5 (0/18/82)
3.2	1.2	1.5	1.0	3.5 (0/17/83)
2.9	0.92	2.2	1.0	2.4 (0/21/79)
3.3	1.2	2.9	1.0	2.1 (0/19/81)
3.3	1.2	4.0	0.82	1.3 (0/23/77)
3,3	1.1	5.1	0.59	0.73 (0/18/82)

^aThe major gaseous components are CH₄ (600 Torr), Me₄Ge (20 Torr), and O_2 (10 Torr).

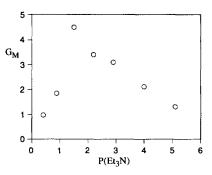


Fig. 6. Overall radiochemical yield ($G_{\rm M}$, in units of $10^{-3}~\mu{\rm mmol}$ J^{-1}) of the germylation products of benzene and toluene plotted vs. $P(Et_3N)$ (Torr).

reactivity ratios that are found to be dependent on Et₃N concentration (Fig. 7).

$$\frac{k_{\rm T}}{k_{\rm B}} = \frac{G_{\rm M}({\rm MeC_6H_4GeMe_3}) \times P({\rm C_6H_6})}{G_{\rm M}({\rm C_6H_5GeMe_3}) \times P({\rm MeC_6H_5})}.$$
 (5)

4. Discussion

4.1. The reagent ion

Me₃Ge⁺ is the only initial ion resulting from the reaction of Me₄Ge with the major reagent ions CH₅⁺ and C₂H₅⁺ formed from methane under CI [15,16] and radiolytic conditions [17]. The exothermicities of the formation processes (Eqs. (6) and (7)) were obtained from thermochemical data in Ref. [14], using ΔH_f° $(Me_3Ge^+) = 167 \text{ kcal mol}^{-1} [18] \text{ and } \Delta H_f^{\circ} (Me_4Ge) =$ $-24.5 \text{ kcal mol}^{-1}$ [19].

$$CH_5^+ + Me_4Ge \rightarrow Me_3Ge^+ + 2CH_4,$$
 (6)

where $\Delta H_{(6)}^{\circ} = -68 \text{ kcal mol}^{-1}$.

$$C_2H_5^+ + Me_4Ge \rightarrow Me_3Ge^+ + C_2H_4 + CH_4,$$
 (7)

where $\Delta H_{(7)}^{\circ} = -37 \text{ kcal mol}^{-1}$. At the pressure of 10^{-4} Torr in the CI ion source conditions of the FTICR instrument, Me₃Ge⁺ is the

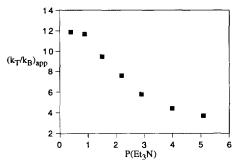


Fig. 7. Apparent relative reactivity ratios from the competitive germylation of benzene and toluene plotted vs. $P(Et_3N)$ (Torr). Values are obtained using Eq. (5).

^bAbsolute yields are in units of $10^{-3} \mu \text{mol J}^{-1}$.

^c(MeO)₃PO was present, in place of Et₃N.

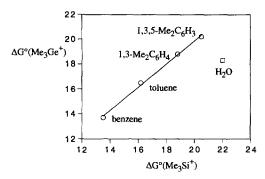


Fig. 8. The correlation between ΔG_{300}° for the association of Me₃Ge⁺ and ΔG_{300}° for the association of Me₃Si⁺ to the selected compounds.

only germylating species. At the much higher Me₄Ge pressure of the radiolytic experiments, an association equilibrium is expected to set up (Eq. (8)) yielding Me₇Ge₂⁺ ions [12,18] which may act as germylating species by Me₄Ge displacement.

$$Me_3Ge^+ + Me_4Ge \rightleftharpoons Me_7Ge_2^+$$
. (8)

 ${\rm Me_3Ge^+}$ is expected to behave exclusively as Lewis acid in view of the rather high PA of its conjugate base (PA of ${\rm Me_2Ge=CH_2}$ equals to 206 kcal ${\rm mol^{-1}}$ [20]). Accordingly, proton transfer from ${\rm Me_3Ge^+}$ to toluene is calculated to be endothermic by 16 kcal ${\rm mol^{-1}}$ (PA of toluene equals to 190 kcal ${\rm mol^{-1}}$ [14]). The exclusive Lewis acid character of ${\rm Me_3Ge^+}$ toward the selected substrates makes the apparent rate constant ratios $k_{\rm T}/k_{\rm B}$ of Fig. 7 a direct measure of the corresponding reaction channels.

4.2. The association of Me₃Ge⁺ to aromatic hydrocarbons

The free energies of binding of Me₃Ge⁺ to aromatic hydrocarbons show an increasing trend in the series from benzene to mesitylene, corresponding to the increasing electron density available at the aromatic ring from the electron donating effect of the methyl substituent(s). The same order corresponds to increasing PA [14] and increasing binding energy to Me₃Si⁺ [21]. The values of ΔG_{300}° for the binding of the two Me₃X⁺ ions (X = Si, Ge) to the aromatic bases are very close to each other and fit the linear relationship drawn in Fig. 8. The slope of 0.93 indicates that the association free energies of Me₃Ge⁺ spread over a narrower range, hence they are slightly less sensitive to the structural features of the aromatic base. Within the approximation that the close values of ΔG_{300}° for the association of Me₃Ge⁺ and Me₃Si⁺ to benzene (13.7 and 13.5 kcal mol⁻¹, respectively) are paralleled by similarly close ΔH° values (23.9 kcal mol⁻¹) [21], a thermochemical cycle can be constructed, allowing the PA of Me₃GeC₆H₅ to be evaluated. It is unfortunately not surprising that the required value of $\Delta H_{\rm f}^{\circ}$

 $Me_3GeC_6H_5$ is missing from the scant and scattered thermochemical data available for germanium compounds. ΔH_f° ($Me_3GeC_6H_5$) was estimated as 8 kcal mol^{-1} by the group increment method using thermochemical data from Ref. [22]. In this way, a PA value of ca. 212 kcal mol^{-1} is derived for $Me_3GeC_6H_5$.

4.3. Mechanism of the germylation reaction and structure of $[Me_3Ge^+ \cdot arene]$ complexes

The closely similar thermodynamic data for the association of Me_3X^+ (X = Ge, Si) to simple aromatics suggests for the [Me_3Ge^+ arene] adduct the same σ -complex structure which several experimental [1–6] and theoretical [23] studies ascribed to gaseous [Me_3Si^+ arene] complexes.

This structural assignment is supported by the reactivity of the [Me₃Ge⁺·arene] adducts. Me₃GeC₆H₆⁺ reacts with H₂O by Me₃Ge⁺ transfer, a process that may be compatible with either a π -complex (**Ia**) or an *ipso-\sigma*-complex (**Ib**) structure of the reactant ion.

However, the $Me_3GeC_6D_6^+$ reaction with Et_3N occurs by D^+ transfer to an appreciable extent and this is strongly indicative of covalent $C_{benzene}$ —Ge bond formation. The overall reactivity pattern fits into a mechanistic scheme (Scheme 2 for C_6H_6 as representative arene) that accounted for the salient features of the corresponding reaction of Me_3Si^+ with aromatic hydrocarbons [1-6].

At variance with π -complex \mathbf{Ia} , expected to react exclusively by $\mathrm{Me_3Ge^+}$ transfer, the σ -complex \mathbf{Ib} may undergo competitive $\mathrm{H^+}$ and $\mathrm{Me_3Ge^+}$ transfer, depending on the features of the neutral reagent. The low PA of $\mathrm{H_2O}$ (166.5 kcal $\mathrm{mol^{-1}}$) [14] prevents $\mathrm{H^+}$ transfer from \mathbf{Ib} whereas $\mathrm{Me_3Ge^+}$ transfer is driven by the intrinsically higher bond energy of Ge–O with respect to Ge–C. The same factor may account for the larger binding free energy of $\mathrm{Me_3Ge^+}$ to $\mathrm{H_2O}$ with respect to $\mathrm{C_6H_6}$, in the reverse order of their PAs (166.5 and

$$Me_3Ge^+ + C_6H_6$$
 $Nu \longrightarrow Me_3GeNu^+ + C_6H_6$
 $B \longrightarrow BH^+ + Me_3GeC_6H_5$

Scheme 2.

181.3 kcal mol⁻¹, respectively) [14]. The use of Et₂N, a strong though sterically hindered nitrogen base, enables deprotonation of **Ib**. The proposed mechanism is supported by the product pattern of the radiolytic germylation where the recovery of neutral germylation products unambiguously proves the formation of a Me₃Ge-C covalent bond through a σ -complex intermediate. The presence of an appropriate base, Et₃N, is required to ensure formation of germylated products. In its absence. traces of oxygenated nucleophiles, unavoidably present, either as adventitious impurities (e.g., H₂O) or as radiolytic products (e.g., H₂O, MeOH, CH₂O, etc.) react with **Ib** exclusively by Me₃Ge⁺ transfer. Accordingly, no aromatic germylated products are formed. However, when Et₃N is added to the gaseous mixtures, two opposing effects on the product yield can be envisaged. On the one hand, Et₃N allows deprotonation of Ib favoring formation of the germylated products. On the other, the amine effectively intercepts the $CH_5^+/C_2H_5^+$ and Me₃Ge⁺ percursors, thus depressing the yields of the intermediates Ib and therefore of the ensuing neutral products. This dual behavior accounts for the dependence of the absolute yields of the germylated products on the partial pressure of Et₃N shown in Fig. 6, which is characterized by a maximum at the Et₃N pressure of ca. 1.5 Torr.

It is worth noting that a highly basic additive such as (MeO)₃PO as well is not effective in yielding germylation products. This result supports an *ipso*-type structure for the germylated arenium intermediate since any isomeric ion obtained by 1,2-H⁺ shift would be deprotonated by (MeO)₃PO leading to observable products (Scheme 3 for MeC₆H₅ as representative arene).

The unwillingness of ion **Ib** to undergo isomerization by 1,2-H⁺ shifts, which contrast with the behavior of alkylated arenium ions [24,25], is traced to the higher stability conferred to **Ib** by the β relationship of the formal positive charge on the arenium ring with respect to the C_{aryi} -Ge bond with an orbital alignment allowing hyperconjugative interaction [26–28].

In conclusion, [Me₃Ge⁺·arene] complexes undergo Me₃Ge⁺ transfer to oxygen nucleophiles and deprotonation by strong nitrogen bases. With a second arene molecule, they engage in reversible Me₃Ge⁺ transfer till equilibrium is reached, as can be observed directly from the ICR kinetic plots. Direct evidence for Me₃Ge⁺ transfer from Me₃GeC₆H₆⁺ to toluene is also obtained from the apparent k_T/k_B ratios from the radiolytic

reactions, which increase as the $\rm Et_3N$ partial pressure is decreased (Fig. 7). This is accounted for by a rather indiscriminate primary attack of $\rm Me_3Ge^+$ at the two substrates to yield an ion population which subsequently tends to shift toward the equilibrium ratio. The $\rm Me_3Ge^+$ transfer to toluene competes with deprotonation by $\rm Et_3N$. Decreasing the $\rm Et_3N$ partial pressure favors the approach to equilibrium by increasing the lifetime of the $\rm [Me_3Ge^+ \cdot arene]$ ions, which cannot, however, be increased indefinitely due to the presence of trace oxygen nucleophiles. The highest apparent k_T/k_B ratio of 12 in Fig. 7 is still far from the equilibrium value of $\rm [MeC_6H_4GeMe_3^+]/[Me_3GeC_6H_6^+] = 35$, expected under the operative reaction conditions.

4.4. Comparison of the gas phase reactivity of Me_3Ge^+ and Me_3Si^+

Several times in the previous sections, the gas phase behavior of Me₃Ge⁺ towards aromatic hydrocarbons has been found to conform to the model Me₃Si⁺ reaction. The similar behavior of the two electrophiles is confirmed also by the positional selectivity of the attack at the ring positions of toluene. In both cases substitution at the ortho position is avoided due to steric hindrance, and the para/meta ratio is ca. 80/20, showing fair selectivity towards the more activated site. However, a noticeable difference emerges from the absolute radiochemical yields of the two reactions. The germylated products are formed with a smaller yield, typically by a factor of ten, with respect to silvlation products under strictly comparable reaction conditions. Whereas the similar binding free energies do not lend support to the hypothesis of a higher barrier for eletrophilic attack by Me₃Ge⁺ with respect to Me₃Si⁺, an explanation can be found in the greater ease of displacement of Me₃Ge⁺ from the arenium complex by oxygen nucleophiles. Such a feature was recently exploited to perform a silylation reaction via Me₃Ge⁺ displacement from Me₃GeC₆H₅, thus obtaining for the first time silylated products without the assistance of a nitrogen base [6]. The high mobility of Me₃Ge⁺ is shown in the reported reactions of Me₃SiC₆H₅GeMe₃⁺ with H₂O and MeO(SiMe₃)GeMe₃⁺ with (MeO)₃PO. Although the heterolytic cleavage and transfer of Me₃Ge⁺ is not strictly comparable to the Me₃Si⁺ reaction as they yield different ionic and neutral products, still it appears significant that the former reaction prevails by a noticeable extent.

5. Conclusions

The gas-phase behavior of Me₃Ge⁺ ions toward aromatic hydrocarbons has shown striking similarities to the corresponding Me₃Si⁺ reaction. This conclusion

emerges primarily from the close values of the free energies of binding of Me_3X^+ (X = Ge, Si) to the same aromatic compound, the only difference lying in the barely detectable smaller sensitivity of the Me₃Ge⁺ association to the structural features of the compounds in the series benzene/toluene/m-xylene/mesitylene. The mechanistic pattern leading to aromatic substitution products was elucidated by the combined information from the FTICR and radiolytic techniques. The major features can be summarized as follows: (i) Me₃Ge⁺ reacts at the aromatic ring giving a σ -complex intermediate; (ii) this primary intermediate retains the hydrogen on the germylated carbon, showing no tendency to isomerize by 1,2-H+ shifts; and (iii) the ipso-type σ -complex may evolve either by deprotonation by strong nitrogen bases or by degermylation by oxygen nucleophiles, the latter an obviously blind reaction channel. All gathered evidence point to this last step as responsible for the major differences observed between the Me₃Ge⁺ and Me₃Si⁺ reaction. In fact, heterolytic cleavage of the C-Ge bond assisted by oxygen nucleophiles appears to occur with greater ease than the corresponding C-Si bond cleavage and the Me₃Ge⁺ group appears endowed with greater mobility than its silicon analogue. In the absence of pertinent thermodynamic and kinetic data, reasons accounting for this different behavior, including the role of the more expanded d orbitals on germanium, can only be guessed.

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